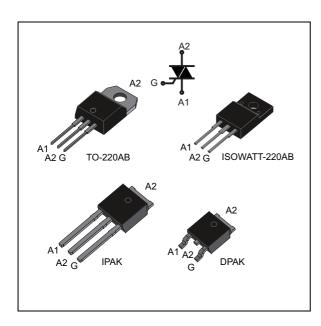




4 A Triacs

Datasheet - production data



Features

- Three quadrants Triac
- 600 to 800 V V_{DRM}/V_{RRM}
- UL certified (ref. file E81734)

Applications

- · General purpose AC inductive loads
- Motor control circuits
- Small home appliances

Description

Based on ST's Snubberless / Logic level technology providing high commutation performances, the T4 series is suitable for use on AC inductive loads. They are recommended for applications using universal motors, electro valves, kitchen aid equipments, power tools, dishwashers. Available in a fully insulated package, the T4yy-xxxW version complies with UL standards (ref.E81734).

Table 1. Main characteristics

Symbol	Value	Unit
I _{T(rms)}	4	А
V_{DRM}, V_{RRM}	600 to 800	V
I _{GT}	5 to 35	mA

Table 2. Device summary

Symbol	Marking
T405-xxxB	
T405-xxxB-TR	
T405-xxxH	
T405-xxxT	
T405-xxxW	
T410-xxxB	
T410-xxxB-TR	
T410-xxxH	see Table 12
T410-xxxT	
T410-xxxW	
T435-xxxB	
T435-xxxB-TR	
T435-xxxH	
T435-xxxT	
T435-xxxW	

xxx = Voltage: 600 V, 700 V or 800 V (see *Table 11*).

Characteristics T4 series

1 Characteristics

Table 3. Absolute maximum ratings ($T_j = 25$ °C unless otherwise stated)

Symbol	Paramo	eter		Value	Unit
I _{T(rms)}	On-state rms current	IPAK, DPAK, TO-220AB	T _C = 110 °C	4	А
1(11113)	(full sine wave)	ISOWATT220AB	T _c = 105 °C		
1.	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	30	Α
I _{TSM}	current (full cycle, T _j initial = 25 °C)	F = 60 Hz	t = 16.7 ms	31	^
l ² t	I ² t value for fusing	t _p = 10 ms	5.1	A²s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$	F = 120 Hz	T _j = 125 °C	50	A/µs
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 125 °C	4	Α
P _{G(AV)}	Average gate power dissipation	1	W		
T _{stg} T _j	Storage junction temperature range Operating junction temperature rang		- 40 to + 150 - 40 to + 150	°C	

Table 4. Electrical characteristics ($T_j = 25$ °C, unless otherwise stated)

Symbol	Test conditions	Quadrant			Unit		
Symbol	rest conditions	Quadrant		T405	T410	T435	
I _{GT} ⁽¹⁾	$V_D = 12 \text{ V}, R_L = 30 \Omega$	1 - 11 - 111	Max.	5	10	35	mA
V_{GT}	$V_D = 12 \text{ V}, R_L = 30 \Omega$	1 - 11 - 111	Max.		1.3		V
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k} \Omega, T_j = 125 \text{ °C}$	1 - 11 - 111	Min.		0.2		V
I _H ⁽²⁾	I _T = 100 mA		Max.	10	15	35	mA
I _I	I _G = 1.2 I _{GT}	1 - 111	Max.	10	25	50	mA
'L		II	Max.	15	30	60	ША
dV/dt (2)	$V_D = 67\% V_{DRM}$, gate open	T _j = 125 °C	Min.	20	40	400	V/µs
	$(dV/dt)c = 0.1 V/\mu s$			1.8	2.7		
(dl/dt)c (2)	(dV/dt)c = 10 V/μs	T _j = 125 °C	Min.	0.9	2.0		A/ms
	(without snubber)					2.5	

^{1.} Minimum $\rm I_{GT}$ is guaranteed at 5% of $\rm I_{GT}$ max.

^{2.} For both polarities of A2 referenced to A1

T4 series Characteristics

Table 5. Static characteristics

Symbol	Test conditions	Value	Unit		
V _{TM} ⁽¹⁾	$I_{TM} = 8.5 \text{ A}, t_p = 380 \mu\text{s}$	T _j = 25 °C	Max.	1.56	V
V _{t0} (1)	Threshold voltage	T _j = 125 °C	Max.	0.89	V
R _d ⁽¹⁾	Dynamic resistance	T _j = 125 °C	Max.	120	mΩ
I _{DRM}	V - V	T _j = 25 °C	Max.	5	μΑ
I _{RRM}	$V_{DRM} = V_{RRM}$	T _j = 125 °C	iviax.	1	mA

^{1.} For both polarities of A2 referenced to A1

Table 6. Thermal resistance

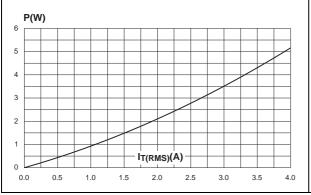
Symbol		Value	Unit		
R _{th(j-c)}	Junction to case (AC)		IPAK, DPAK,TO-220AB	2.6	°C/W
			ISOWATT220AB	4.0	C/VV
_	Junction to ambient (DC) $S^{(1)} = 0.5$ cm^2		DPAK	70	
R _{th(j-a)}	Junction to ambient (DC)		ISOWATT220AB, TO-220AB	60	°C/W
			IPAK	100	

^{1.} S = Copper surface under tab.

Characteristics T4 series

Figure 1. Maximum power dissipation versus RMS on-state current (full cycle)

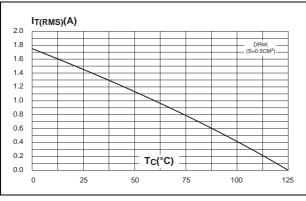
Figure 2. RMS on-state current versus case temperature (full cycle)



1T(RMS)(A)
4.0
3.5
3.0
1.5
2.0
1.5
1.0
0.5
0.0
0
25
50
75
100
125

Figure 3. RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35µm) (full cycle)

Figure 4. Relative variation of thermal impedance versus pulse duration



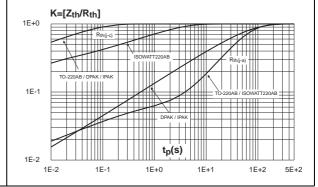
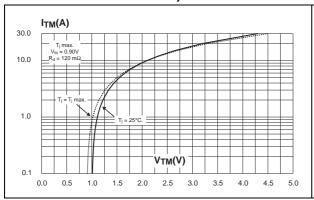
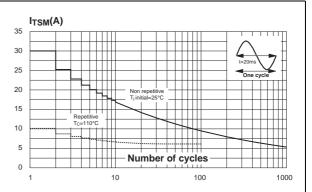


Figure 5. On-state characteristics (maximum values)

Figure 6. Surge peak on-state current versus number of cycles

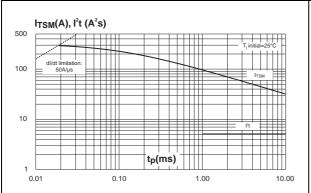




T4 series Characteristics

Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_{\rm p}$ < 10 ms and corresponding value of l^2t

Figure 8. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)



IGT, IH, IL[Tj] / IGT, IH, IL[Tj=25°C]

2.0

1.5

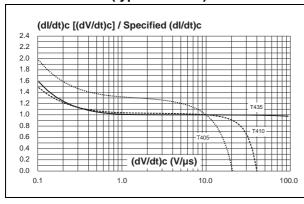
1.0

0.5

-40 -20 0 20 40 60 80 100 120 140

Figure 9. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)

Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature



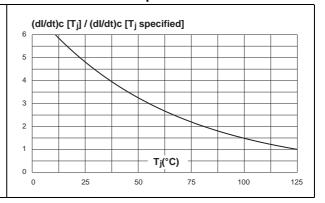
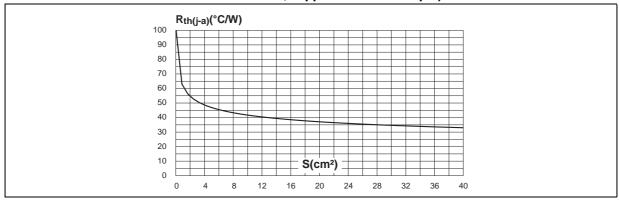


Figure 11. DPAK thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 µm)



2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Recommended torque: 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

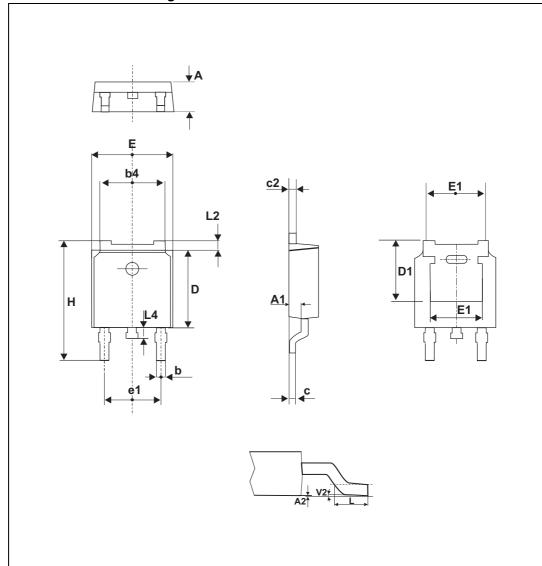


Figure 12. DPAK dimension definitions

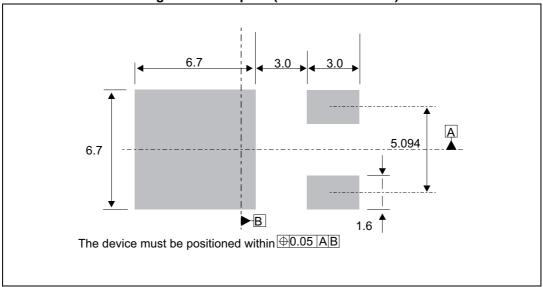
Note:

this package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 7. DPAK dimension values

		Dimensions								
Ref.		Millimeters			Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	2.18		2.40	0.086		0.094				
A1	0.90		1.10	0.035		0.043				
A2	0.03		0.23	0.001		0.009				
b	0.64		0.90	0.025		0.035				
b4	4.95		5.46	0.195		0.215				
С	0.46		0.61	0.018		0.024				
c2	0.46		0.60	0.018		0.023				
D	5.97		6.22	0.235		0.244				
D1	5.10			0.201						
Е	6.35		6.73	0.250		0.264				
E1		4.32			0.170					
e1	4.40		4.70	0.173		0.185				
Н	9.35		10.40	0.368		0.409				
L	1.00		1.78	0.039		0.070				
L2			1.27			0.05				
L4	0.60		1.02	0.023		0.040				
V2	0°		8°	0°		8°				

Figure 13. Footprint (dimensions in mm)



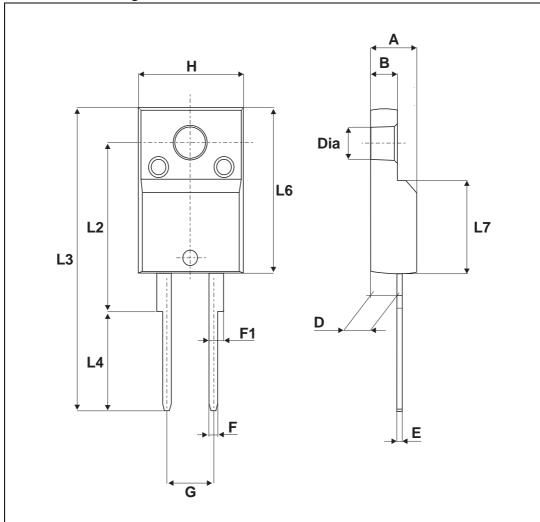


Figure 14. ISOWATT220AB dimension definitions

T4 series Package information

Table 8. ISOWATT220AB dimension values

		Dimensions								
Ref.		Millimeters			Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	4.40		4.60	0.173		0.181				
В	2.50		2.70	0.098		0.106				
D	2.50		2.75	0.098		0.108				
Е	0.40		0.70	0.016		0.028				
F	0.75		1.00	0.030		0.039				
F1	1.15		1.70	0.045		0.067				
F2	1.15		1.70	0.045		0.067				
G	4.95		5.20	0.195		0.205				
G1	2.40		2.70	0.094		0.106				
Н	10.00		10.40	0.394		0.409				
L2		16.00 typ.			0.630 typ.					
L3	28.60		30.60	1.125		1.205				
L4	9.80		10.60	0.386		0.417				
L6	15.90		16.40	0.626		0.646				
L7	9.00		9.30	0.354		0.366				
Diam	3.00		3.20	0.118		0.126				

9/17

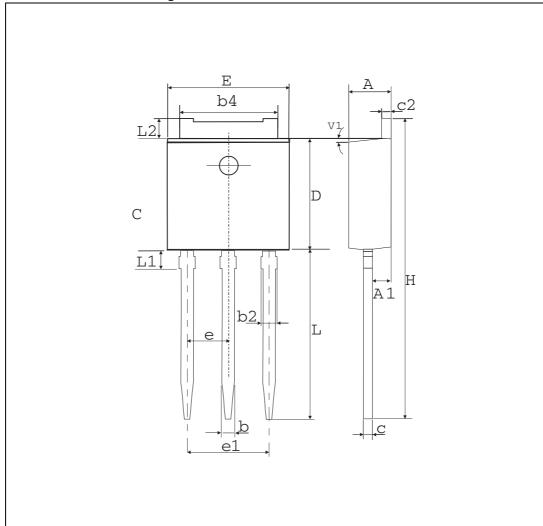


Figure 15. IPAK dimension definitions

Note:

this package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 9. IPAK dimension values

		Dimensions								
Ref.		Millimeters			Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	2.20		2.40	0.086		0.094				
A1	0.90		1.10	0.035		0.043				
b	0.64		0.90	0.025		0.035				
b2			0.95			0.037				
b4	5.20		5.43	0.204		0.213				
С	0.45		0.60	0.017		0.023				
c2	0.46		0.60	0.018		0.023				
D	6		6.20	0.236		0.244				
E	6.40		6.70	0.252		0.263				
е		2.28			0.090					
e1	4.40		4.60	0.173		0.181				
Н		16.10			0.634					
L	9		9.60	0.354		0.377				
L1	0.8		1.20	0.031		0.047				
L2		0.80	1.25		0.031	0.049				
V1		10°			10°					

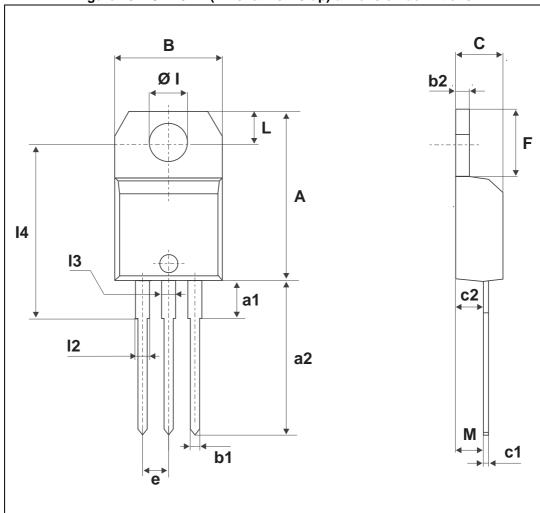


Figure 16. TO-220AB (NIns. & Ins. 20-up) dimension definitions

T4 series Package information

Table 10. TO-220AB (Nins. & Ins. 20-up) dimension values

		Dimensions								
Ref.		Millimeters			Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	15.20		15.90	0.598		0.625				
a1		3.75			0.147					
a2	13.00		14.00	0.511		0.551				
В	10.00		10.40	0.393		0.409				
b1	0.61		0.88	0.024		0.034				
b2	1.23		1.32	0.048		0.051				
С	4.40		4.60	0.173		0.181				
c1	0.49		0.70	0.019		0.027				
c2	2.40		2.72	0.094		0.107				
е	2.40		2.70	0.094		0.106				
F	6.20		6.60	0.244		0.259				
ØI	3.75		3.85	0.147		0.151				
14	15.80	16.40	16.80	0.622	0.646	0.661				
L	2.65		2.95	0.104		0.116				
12	1.14		1.70	0.044		0.066				
13	1.14		1.70	0.044		0.066				
М		2.60			0.102					

Ordering information T4 series

3 Ordering information

Figure 17. Order information scheme

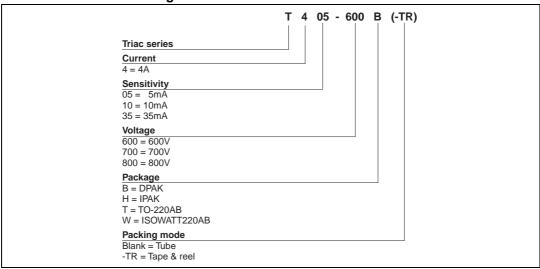


Table 11. Product Selector

Part Number	Voltage (xxx)			Compitivity	T	Dookses
Part Number	600 V	700 V	800 V	Sensitivity	Туре	Package
T405-xxxB	Х	Х	Х	5 mA	Logic level	DPAK
T405-xxxB-TR	Х	Х	Х	5 mA	Logic level	DPAK
T405-xxxH	Х		Х	5 mA	Logic level	IPAK
T405-xxxT	Х			5 mA	Logic level	TO-220AB
T405-xxxW	Х			5 mA	Logic level	ISOWATT220AB
T410-xxxB	Х		Х	10 mA	Logic Level	DPAK
T410-xxxB-TR	Х		Х	10 mA	Logic Level	DPAK
T410-xxxH	Х		Х	10 mA	Logic Level	IPAK
T410-xxxT	Х	Х	Х	10 mA	Logic Level	TO-220AB
T410-xxxW	Х			10 mA	Logic Level	ISOWATT220AB
T435-xxxB	Х	Х	Х	35 mA	Snubberless	DPAK
T435-xxxB-TR	Х	Х	Х	35 mA	Snubberless	DPAK
T435-xxxH	Х		Х	35 mA	Snubberless	IPAK
T435-xxxT	Х		Х	35 mA	Snubberless	TO-220AB
T435-xxxW	Х		Х	35 mA	Snubberless	ISOWATT220AB

Blank = Unavailable

Table 12. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode		
T405-600B	T4 0560						
T410-600B	T4 1060						
T435-600B	T4 3560						
T405-700B	T4 0570				75	Tube	
T435-700B	T4 3570			75	Tube		
T405-800B	T4 0580						
T410-800B	T4 1080						
T435-800B	T4 3580	DPAK	0.2 ~				
T405-600B-TR	T4 0560	DPAK	0.3 g				
T410-600B-TR	T4 1060			2500	Tape and reel		
T435-600B-TR	T4 3560						
T405-700B-TR	T4 0570						
T435-700B-TR	T4 3570						
T405-800B-TR	T4 0580						
T410-800B-TR	T4 1080						
T435-800B-TR	T4 3580						
T405-600H	T4 0560					75	
T410-600H	T4 1060						
T435-600H	T4 3560	IPAK	0.4	0.4	0.4		
T405-800H	T4 0580	IPAK	0.4				
T410-800H	T4 1080						
T435-800H	T4 3580				Tube		
T405-600T	T405-600T						
T410-600T	T410-600T						
T435-600T	T435-600T	TO 220AB	0.0				
T410-700T	T410-700T	TO-220AB	2.3				
T410-800T	T410-800T			5 0			
T435-800T	T435-800T			50			
T405-600W	T405-600W						
T410-600W	T410-600W	ISOMATTOOOAD	2.4				
T435-600W	T435-600W	ISOWATT220AB	2.1				
T435-800W	T435-800W						

Revision history T4 series

4 Revision history

Table 13. Document revision history

Date	Revision	Changes
Jun-2003	2	Last updated.
25-Mar-2005	3	Layout updated0 No content change.
25-Jan-2006	4	Markings changed in <i>Table 12</i> .
14-May-2014	5	Updated DPAK and IPAK package information and reformatted to current standard.
11-Feb-2015	6	Updated package silhouettes in cover page.

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